

650V SiC Schottky Diode

Amp+[™] Features

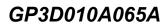
- Unipolar rectifier with surge current
- Zero reverse recovery current
- · Fast, temperature-independent switching
- Avalanche tested to 67mJ*

Amp+[™] Benefits

- Zero switching loss
- Higher efficiency
- Smaller heat sink
- Easy to parallel

Amp+[™] Applications

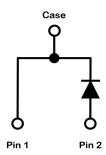
- General Purpose
- · Switched mode power supplies, UPS
- Power factor correction
- Output rectification



VDC	650 V
Q _c	26 nC
I _F	10 A
T _j ,max	175 °C

Package





Part #	Package	Marking
GP3D010A065A	TO-220-2L	3D010A065



Maximum Ratings, at Ti=25 °C, unless otherwise specified

Symbol	Conditions	Values	Unit	
	T _c =25 °C, T _j =175 °C	29		
I _F **	T _C =125 °C, T _j =175 °C	15	А	
	T _C =150 °C, T _j =175 °C	10		
1	T _C =25 °C, t _p =8.3 ms	80		
IFSM	T _C =110 °C, t _p =8.3 ms	70	— A	
I _{F,max}	T _C =25 °C, t _p =10 μs	575	A	
∫i²dt	T _C =25 °C, t _p =8.3 ms	27	A2	
	T _C =110 °C, t _p =8.3 ms	20	A ² s	
V _{RRM}	T _j =25 °C	650	V	
dv/dt	Turn-on slew rate, repetitive	200	V/ns	
P _{tot} **	T _C =25 °C	104	W	
T _j , T _{storage}	Continuous	-55175	°C	
T _{solder}	Wave soldering leads	260	°C	
	M3 Screw	1	N-m	
	I_{F}^{**} I_{FSM} $I_{F,max}$ $\int i^{2} dt$ V_{RRM} dv/dt P_{tot}^{**} $T_{j}, T_{storage}$	$\begin{tabular}{ c c c c c c } \hline T_{c}=25 \ ^{\circ}\text{C}, \ T_{j}=175 \ ^{\circ}\text{C} \\ \hline T_{c}=125 \ ^{\circ}\text{C}, \ T_{j}=175 \ ^{\circ}\text{C} \\ \hline T_{c}=150 \ ^{\circ}\text{C}, \ T_{j}=175 \ ^{\circ}\text{C} \\ \hline T_{c}=150 \ ^{\circ}\text{C}, \ T_{j}=175 \ ^{\circ}\text{C} \\ \hline T_{c}=25 \ ^{\circ}\text{C}, \ t_{p}=8.3 \ \text{ms} \\ \hline T_{c}=110 \ ^{\circ}\text{C}, \ t_{p}=8.3 \ \text{ms} \\ \hline T_{c}=25 \ ^{\circ}\text{C}, \ t_{p}=10 \ \mu\text{s} \\ \hline T_{c}=110 \ ^{\circ}\text{C}, \ t_{p}=8.3 \ \text{ms} \\ \hline T_{c}=110 \ ^{\circ}\text{C}, \ t_{p}=8.3 \ \text{ms} \\ \hline T_{c}=110 \ ^{\circ}\text{C}, \ t_{p}=8.3 \ \text{ms} \\ \hline T_{c}=110 \ ^{\circ}\text{C}, \ t_{p}=8.3 \ \text{ms} \\ \hline V_{RRM} \ T_{j}=25 \ ^{\circ}\text{C} \\ \hline dv/dt \ Turn-on \ slew \ rate, \ repetitive \\ \hline P_{tot}^{**} \ T_{c}=25 \ ^{\circ}\text{C} \\ \hline T_{j}, \ T_{storage} \ \hline Continuous \\ \hline T_{solder} \ Wave \ soldering \ leads \\ \hline \end{tabular}$	$I_{F}^{**} = \begin{bmatrix} T_{c}=25 \ ^{\circ}C, \ T_{j}=175 \ ^{\circ}C & 29 \\ T_{c}=125 \ ^{\circ}C, \ T_{j}=175 \ ^{\circ}C & 15 \\ T_{c}=150 \ ^{\circ}C, \ T_{j}=175 \ ^{\circ}C & 10 \\ \hline T_{c}=150 \ ^{\circ}C, \ T_{j}=175 \ ^{\circ}C & 10 \\ \hline T_{c}=110 \ ^{\circ}C, \ T_{p}=8.3 \ ^{ms} & 80 \\ \hline T_{c}=110 \ ^{\circ}C, \ T_{p}=8.3 \ ^{ms} & 70 \\ \hline I_{F,max} & T_{c}=25 \ ^{\circ}C, \ T_{p}=10 \ ^{\mu}s & 575 \\ \hline f_{i}^{2}dt & \hline T_{c}=25 \ ^{\circ}C, \ T_{p}=8.3 \ ^{ms} & 27 \\ \hline T_{c}=110 \ ^{\circ}C, \ T_{p}=8.3 \ ^{ms} & 20 \\ \hline V_{RRM} & T_{j}=25 \ ^{\circ}C & 650 \\ \hline dv/dt & \hline Turn-on \ slew \ rate, \ repetitive & 200 \\ \hline P_{tot}^{**} & T_{c}=25 \ ^{\circ}C & 104 \\ \hline T_{j}, \ T_{storage} & \hline Continuous & -55175 \\ \hline T_{solder} & Wave \ soldering \ leads & 260 \\ \hline \end{bmatrix}$	

Notes:

* EAS of 67 mJ is based on starting Tj = 25°C, L = 1.0 mH, IAS = 11.58 A, V = 50 V.

** Typical R_{thJC} used

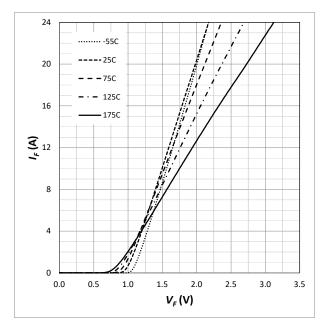
Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	Unit
DC blocking voltage	V _{DC}	T _j =25 °C	650	-	-	V
		I _F =10A, T _j =25 °C	-	1.50	1.60	
Diode forward voltage		I _F =10A, T _j =125 °C	-	1.59	-	V
		I _F =10A, T _j =175 °C	-	1.72	2.20	
Reverse current	I _R	V _R =650V, T _j =25 °C	-	2	25	μΑ
		V _R =650V, T _j =125 °C	-	11	-	
		V _R =650V, T _j =175 °C	-	36	250	
Total capacitive charge	Q _C	V _R =400V, T _j =25 °C	-	26	-	nC
		V _R =1V, f=1 MHz	-	419	-	
Total capacitance	С	V _R =200V, f=1 MHz	-	51	-	pF
		V _R =400V, f=1 MHz	-	43	-	

Electrical Characteristics, at T_i=25 °C, unless otherwise specified

Thermal Characteristics

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	onit
Thermal resistance, junction-case	R_{thJC}	-	-	1.44	2.04	°C/W

Typical Performance



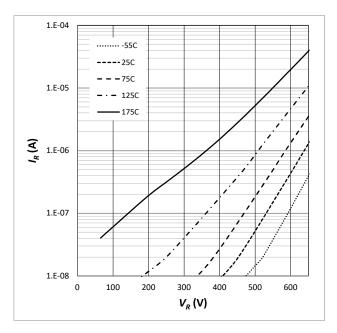
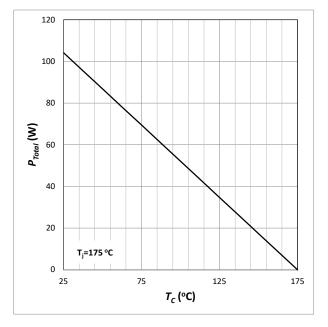




Fig. 2 Reverse Characteristics (parameterized on T_i)



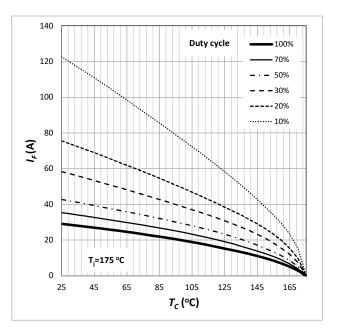
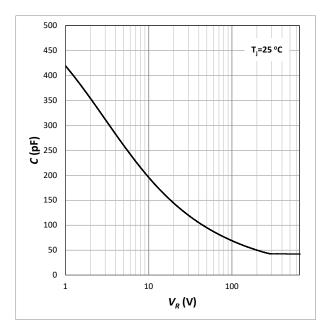


Fig. 3 Power Derating

Fig. 4 Current Derating



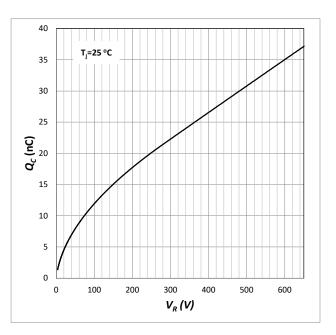
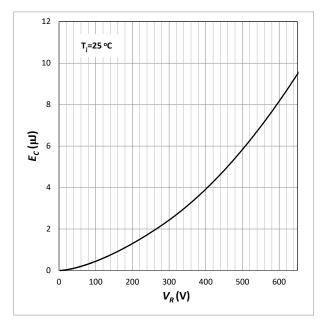


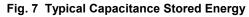
Fig. 5 Capacitance

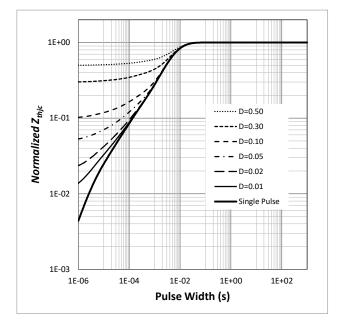
Fig. 6 Capacitive Charge

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GP3D010A065A

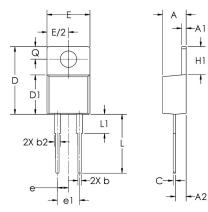


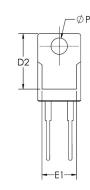






Package Dimensions TO-220-2L





Sum Millimete		neters	Inches		
Sym	Min	Max	Min	Max	
А	3.56	4.83	0.140	0.190	
A1	0.51	1.40	0.020	0.055	
A2	2.03	2.92	0.080	0.115	
b	0.38	1.02	0.015	0.040	
b2	1.02	1.78	0.040	0.070	
С	0.36	0.76	0.014	0.030	
D	14.22	16.51	0.560	0.650	
D1	8.38	9.40	0.330	0.370	
D2	12.19	13.13	0.480	0.517	
E	9.65	10.67	0.380	0.420	
E1	6.86	8.89	0.270	0.350	
е	2.54	BSC	.100 BSC		
e1	5.08	BSC	.200	BSC	
H1	5.84	6.86	0.230	0.270	
L	12.57	14.73	0.495	0.580	
L1	3.60	6.35	0.142	0.250	
ØP	3.53	4.09	0.139	0.161	
Q	2.54	3.43	0.100	0.135	

Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.SemiQ.com.

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